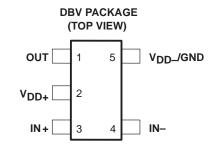
- Output Swing Includes Both Supply Rails
- Low Noise . . . 21 nV/ $\sqrt{\text{Hz}}$  Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Very Low Power . . . 11 μA Per Channel Typ
- Common-Mode Input Voltage Range Includes Negative Rail
- Wide Supply Voltage Range 2.7 V to 10 V
- Available in the SOT-23 Package
- Macromodel Included

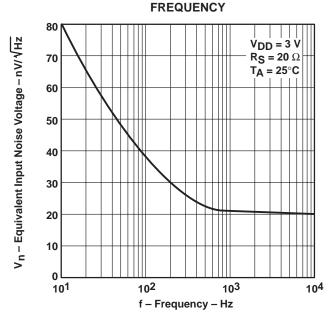
#### description

The TLV2711 is a single low-voltage operational amplifier available in the SOT-23 package. It consumes only 11  $\mu A$  (typ) of supply current and is ideal for battery-power applications. Looking at Figure 1, the TLV2711 has a 3-V noise level of 21 nV/ $\sqrt{\text{Hz}}$  at 1 kHz; five times lower than competitive SOT-23 micropower solutions. The device exhibits rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLV2711 is fully characterized at 3 V and 5 V and is optimized for low-voltage applications.

The TLV2711, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels combined with 3-V operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs).



# EQUIVALENT INPUT NOISE VOLTAGE†



† For all curves where  $V_{DD} = 5$  V, all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3$  V, all loads are referenced to 1.5 V.

Figure 1. Equivalent Input Noise Voltage Versus Frequency

With a total area of 5.6mm<sup>2</sup>, the SOT-23 package only requires one-third the board space of the standard 8-pin SOIC package. This ultra-small package allows designers to place single amplifiers very close to the signal source, minimizing noise pick-up from long PCB traces.

#### **AVAILABLE OPTIONS**

|   | т.            | Viemey AT 25°C              | PACKAGED DEVICES          | SYMBOL   | CHIP FORM‡ |
|---|---------------|-----------------------------|---------------------------|----------|------------|
|   | TA            | V <sub>IO</sub> max AT 25°C | SOT-23 (DBV) <sup>†</sup> | STIVIBUL | (Y)        |
|   | 0°C to 70°C   | 3 mV                        | TLV2711CDBV               | VAJC     | TI V2711Y  |
| 1 | -40°C to 85°C | 3 mV                        | TLV2711IDBV               | VAJI     | ILV2/III   |

<sup>†</sup>The DBV package available in tape and reel only.

<sup>‡</sup> Chip forms are tested at  $T_A = 25^{\circ}C$  only.



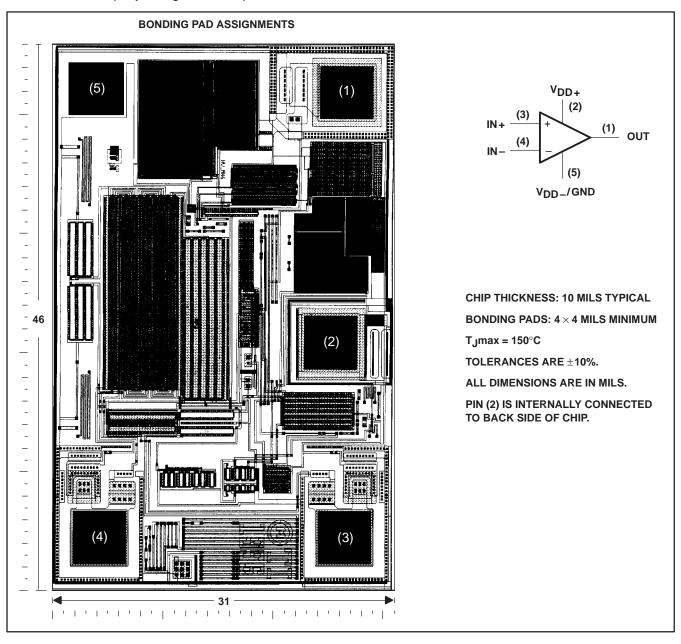
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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TEXAS INSTRUMENTS

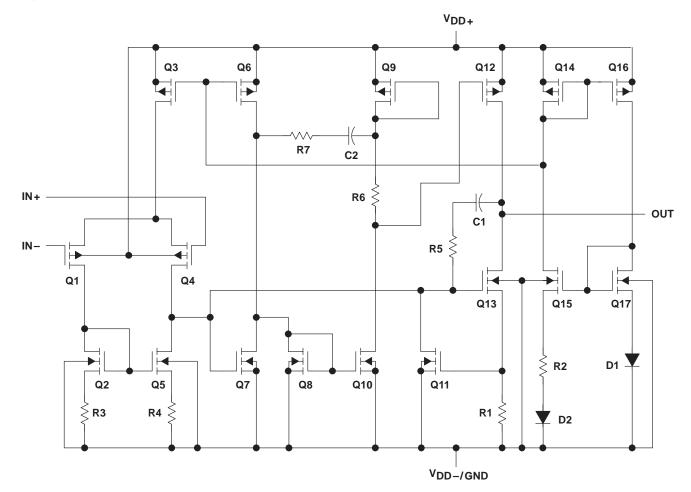
#### **TLV2711Y chip information**

This chip, when properly assembled, displays characteristics similar to the TLV2711C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.





## equivalent schematic



| COMPONENT COUNT <sup>†</sup> |    |  |  |  |  |  |
|------------------------------|----|--|--|--|--|--|
| Transistors                  | 23 |  |  |  |  |  |
| Diodes                       | 6  |  |  |  |  |  |
| Resistors                    | 11 |  |  |  |  |  |
| Capacitors                   | 2  |  |  |  |  |  |

<sup>†</sup> Includes both amplifiers and all ESD, bias, and trim circuitry

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage, V <sub>DD</sub> (see Note 1)                              |                              |
|---|------------------------------|
| Differential input voltage, V <sub>ID</sub> (see Note 2)                  | ±V <sub>DD</sub>             |
| Input voltage range, V <sub>I</sub> (any input, see Note 1)               |                              |
| Input current, I <sub>I</sub> (each input)                                | ±5 mA                        |
| Output current, I <sub>O</sub>  | ±50 mA                       |
| Total current into V <sub>DD+</sub>                                       | ±50 mA                       |
| Total current out of V <sub>DD</sub>                                      | ±50 mA                       |
| Duration of short-circuit current (at or below) 25°C (see Note 3)         | unlimited                    |
| Continuous total power dissipation  | See Dissipation Rating Table |
| Operating free-air temperature range, T <sub>A</sub> : TLV2711C           | 0°C to 70°C                  |
| TLV2711I  | –40°C to 85°C                |
| Storage temperature range, T <sub>stg</sub>                               | –65°C to 150°C               |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DBV package |                              |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to V<sub>DD</sub> \_.
  - 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below V<sub>DD</sub> = 0.3 V.
  - 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

#### **DISSIPATION RATING TABLE**

| PACKAGE | $T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ Power rating | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|---------|--|--|---------------------------------------|---------------------------------------|
| DBV     | 150 mW   | 1.2 mW/°C                                      | 96 mW                                 | 78 mW                                 |

#### recommended operating conditions

|  | TLV2711C<br>MIN MAX |                       | TI                | UNIT                  |      |
|--|---------------------|-----------------------|-------------------|-----------------------|------|
|  |                     |                       | MIN               | MAX                   | UNII |
| Supply voltage, V <sub>DD</sub> (see Note 1)   | 2.7                 | 10                    | 2.7               | 10                    | V    |
| Input voltage range, V <sub>I</sub>            | $V_{DD-}$           | V <sub>DD+</sub> -1.3 | V <sub>DD</sub> - | V <sub>DD+</sub> -1.3 | V    |
| Common-mode input voltage, V <sub>IC</sub>     | V <sub>DD</sub> _   | V <sub>DD+</sub> -1.3 | V <sub>DD</sub> _ | V <sub>DD+</sub> -1.3 | V    |
| Operating free-air temperature, T <sub>A</sub> | 0                   | 70                    | -40               | 85                    | °C   |

NOTE 1: All voltage values, except differential voltages, are with respect to VDD -.



# electrical characteristics at specified free-air temperature, $V_{DD}$ = 3 V (unless otherwise noted)

|                   | DADAMETED   | TEST COND   | TEST CONDITIONS                       |                    | Т           | LV27110          | C   | Т           | LV2711           | I        |       |
|-------------------|---|---|---------------------------------------|--------------------|-------------|------------------|-----|-------------|------------------|----------|-------|
|                   | PARAMETER   | TEST COND   | IIIONS                                | T <sub>A</sub> †   | MIN         | TYP              | MAX | MIN         | TYP              | MAX      | UNIT  |
| ۷ <sub>IO</sub>   | Input offset voltage                                    |   |                                       |                    |             | 0.4              | 3   |             | 0.4              | 3        | mV    |
| αVIO              | Temperature coefficient of input offset voltage         |   |                                       | Full range         |             | 1                |     |             | 1                |          | μV/°C |
|                   | Input offset voltage<br>long-term drift<br>(see Note 4) | $V_{DD\pm} = \pm 1.5 \text{ V},$<br>$V_{O} = 0,$          | $V_{IC} = 0$ ,<br>RS = 50 $\Omega$    | 25°C               |             | 0.003            |     |             | 0.003            |          | μV/mo |
| IIO               | Input offset current                                    |   |                                       | 25°C               |             | 0.5              | 60  |             | 0.5              | 60       |       |
| 10                | input onset ourient                                     |   |                                       | Full range         |             |                  | 150 |             |                  | 150      | pА    |
| I <sub>IB</sub>   | Input bias current                                      |   |                                       | 25°C               |             |                  | 60  |             |                  | 60       | PΑ    |
| מוי               | Input bias current                                      |   |                                       | Full range         |             | 1                | 150 |             | 1                | 150      |       |
| \/                | Common-mode input                                       | mmon-mode input   | D- 50.0                               | 25°C               | 0<br>to 2   | -0.3<br>to 2.2   |     | 0<br>to 2   | -0.3<br>to 2.2   |          | V     |
| VICR              | voltage range   | . IIVIO I < 5 mV  | $R_S = 50 \Omega$                     | Full range         | 0<br>to 1.7 |                  |     | 0<br>to 1.7 |                  |          | V     |
|                   |   | I <sub>OH</sub> = -100 μA                                 |                                       | 25°C               |             | 2.94             |     |             | 2.94             |          |       |
| Vон               | High-level output voltage                               |   |                                       | 25°C               |             | 2.85             |     |             | 2.85             |          | V     |
|                   | voitage   | I <sub>OH</sub> = -250 μA                                 |                                       | Full range         | 2.6         |                  |     | 2.6         |                  |          |       |
|                   |   | V <sub>IC</sub> = 1.5 V,                                  | I <sub>OL</sub> = 50 μA               | 25°C               |             | 15               |     |             | 15               |          |       |
| VOL               | Low-level output voltage                                | V 4.5.V   |                                       | 25°C               |             | 150              |     |             | 150              |          | mV    |
|                   | voltage   | V <sub>IC</sub> = 1.5 V,                                  | $I_{OL} = 500 \mu\text{A}$            | Full range         |             |                  | 500 |             |                  | 500      |       |
|                   | Large-signal<br>differential voltage                    | I voltage $V_{IC} = 1.5 \text{ V},$                       | 5 401 ot                              | 25°C               | 3           | 7                |     | 3           | 7                |          |       |
| AVD               |   |   | $R_L = 10 \text{ k}\Omega^{\ddagger}$ | Full range         | 1           |                  |     | 1           |                  |          | V/mV  |
|                   | amplification   | 1 10 2 1  | $R_L = 1 M\Omega^{\ddagger}$          | 25°C               |             | 600              |     |             | 600              |          |       |
| r <sub>i(d)</sub> | Differential input resistance                           |   |                                       | 25°C               |             | 10 <sup>12</sup> |     |             | 10 <sup>12</sup> |          | Ω     |
| r <sub>i(c)</sub> | Common-mode input resistance                            |   |                                       | 25°C               |             | 10 <sup>12</sup> |     |             | 1012             |          | Ω     |
| c <sub>i(c)</sub> | Common-mode input capacitance                           | f = 10 kHz,   |                                       | 25°C               |             | 5                |     |             | 5                |          | pF    |
| z <sub>O</sub>    | Closed-loop output impedance                            | f = 7 kHz,  | A <sub>V</sub> = 1                    | 25°C               |             | 200              |     |             | 200              |          | Ω     |
| CMRR              | Common-mode rejection ratio                             | $V_{IC} = 0 \text{ to } 1.7 \text{ V},$ $R_S = 50 \Omega$ | V <sub>O</sub> = 1.5 V,               | 25°C<br>Full range | 65<br>60    | 83               |     | 65<br>60    | 83               |          | dB    |
|                   |   |   |                                       | _                  |             |                  |     | $\vdash$    |                  |          |       |
| ksvr              | Supply voltage rejection ratio                          | $V_{DD} = 2.7 \text{ V to 8 V},$<br>No load               | $V_{IC} = V_{DD}/2$                   | 25°C<br>Full range | 80<br>80    | 95               |     | 80<br>80    | 95               |          | dB    |
|                   | (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )                   |   |                                       | 25°C               | 00          | 11               | 25  | - 00        | 11               | 2F       |       |
| IDD               | Supply current  | V <sub>O</sub> = 1.5 V,                                   | No load                               |                    |             | 11               |     |             | 11               | 25<br>30 | μΑ    |
|                   |   |   |                                       | Full range         |             |                  | 30  |             |                  | 30       |       |

<sup>†</sup> Full range for the TLV2711C is 0°C to 70°C. Full range for the TLV2711I is – 40°C to 85°C.



<sup>‡</sup>Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^{\circ}C$  extrapolated to  $T_A = 25^{\circ}C$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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# operating characteristics at specified free-air temperature, $V_{DD} = 3 V$ (unless otherwise noted)

|                    | PARAMETER                                   | TEST COND   | ITIONS  | <b>+</b> +       | Т     | LV27110 | С   | 1     | LV2711 | I   | UNIT               |  |
|--------------------|---|---|---|------------------|-------|---------|-----|-------|--------|-----|--------------------|--|
|                    | PARAWETER                                   | TEST COND   | ITIONS  | T <sub>A</sub> † | MIN   | TYP     | MAX | MIN   | TYP    | MAX | UNIT               |  |
|                    |   | V- 44V+040V   | D. 10 kgt                                       | 25°C             | 0.01  | 0.025   |     | 0.01  | 0.025  |     |                    |  |
| SR                 | Slew rate at unity gain                     | $V_{O} = 1.1 \text{ V to } 1.9 \text{ V},  R_{L} = 10 \text{ k}\Omega^{\ddagger}, \\ C_{L} = 100 \text{ pF}^{\ddagger}$ |   | Full<br>range    | 0.005 |         |     | 0.005 |        |     | V/μs               |  |
| Vn                 | Equivalent input noise                      | f = 10 Hz   |   | 25°C             |       | 80      |     |       | 80     |     | nV/√ <del>Hz</del> |  |
|                    | voltage                                     | f = 1 kHz   |   | 25°C             |       | 22      |     |       | 22     |     | nv/√Hz             |  |
| V                  | Peak-to-peak equivalent input noise voltage | f = 0.1 Hz to 1 Hz  |   | 25°C             |       | 660     |     |       | 660    |     | nV                 |  |
| V <sub>N(PP)</sub> |   | f = 0.1 Hz to 10 Hz   |   | 25°C             |       | 880     |     |       | 880    |     |                    |  |
| In                 | Equivalent input noise current              |   |   | 25°C             |       | 0.6     |     |       | 0.6    |     | fA/√ <del>Hz</del> |  |
|                    | Gain-bandwidth product                      | f = 10  kHz,<br>$C_L = 100 \text{ pF}^{\ddagger}$   | $R_L = 10 \text{ k}\Omega^{\ddagger}$ ,         | 25°C             |       | 56      |     |       | 56     |     | kHz                |  |
| ВОМ                | Maximum output-swing bandwidth              | $V_{O(PP)} = 1 \text{ V},$ $R_{L} = 10 \text{ k}\Omega^{\ddagger},$   | $A_V = 1,$<br>$C_L = 100 \text{ pF}^{\ddagger}$ | 25°C             |       | 7       |     |       | 7      |     | kHz                |  |
| φm                 | Phase margin at unity gain                  | $R_L = 10 \text{ k}\Omega^{\ddagger}$ ,   | C <sub>L</sub> = 100 pF‡                        | 25°C             |       | 56°     |     |       | 56°    | ·   |                    |  |
|                    | Gain margin                                 |   |   | 25°C             |       | 20      |     |       | 20     |     | dB                 |  |

<sup>†</sup> Full range is –40°C to 85°C.

<sup>‡</sup>Referenced to 1.5 V

# electrical characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$ (unless otherwise noted)

|                   | PARAMETER   | TEST CONDITIONS   |  | T. †             | Т           | LV27110        | С   | ٦           | LV2711         | I   | UNIT  |
|-------------------|---|---|--|------------------|-------------|----------------|-----|-------------|----------------|-----|-------|
|                   | PARAMETER   | TEST COND   | ITIONS   | T <sub>A</sub> † | MIN         | TYP            | MAX | MIN         | TYP            | MAX | UNIT  |
| V <sub>IO</sub>   | Input offset voltage                                    |   |  |                  |             | 0.45           | 3   |             | 0.45           | 3   | mV    |
| αΛΙΟ              | Temperature coefficient of input offset voltage         |   |  | Full range       |             | 0.5            |     |             | 0.5            |     | μV/°C |
|                   | Input offset voltage<br>long-term drift<br>(see Note 4) | $V_{DD\pm} = \pm 2.5 \text{ V},$<br>$V_{O} = 0,$        | $V_{IC} = 0$ ,<br>R <sub>S</sub> = 50 $\Omega$ | 25°C             |             | 0.003          |     |             | 0.003          |     | μV/mo |
| IIO               | Input offset current                                    |   |  | 25°C             |             | 0.5            | 60  |             | 0.5            | 60  | pА    |
| 10                | Input onset ourrent                                     | ]   |  | Full range       |             |                | 150 |             |                | 150 | p/ t  |
| IIB               | Input bias current                                      |   |  | 25°C             |             | 1              | 60  |             | 1              | 60  | pА    |
| - 'וס             | Input blub building                                     |   |  | Full range       |             |                | 150 |             |                | 150 | P/\   |
| \/                | Common-mode input                                       | <br> V <sub>IO</sub>   ≤5 mV                            | Do 50.0  | 25°C             | 0<br>to 4   | -0.3<br>to 4.2 |     | 0<br>to 4   | -0.3<br>to 4.2 |     | V     |
| VICR              | voltage range   |   | $R_S = 50 \Omega$                              | Full range       | 0<br>to 3.5 |                |     | 0<br>to 3.5 |                |     | V     |
|                   |   | I <sub>OH</sub> = -100 μA                               |  | 25°C             |             | 4.95           |     |             | 4.95           |     |       |
| Vон               | High-level output voltage                               |   |  | 25°C             |             | 4.875          |     |             | 4.875          |     | V     |
| 011               | voltage   | I <sub>OH</sub> = -250 μA                               |  | Full range       | 4.6         |                |     | 4.6         |                |     |       |
|                   |   | V <sub>IC</sub> = 2.5 V,                                | I <sub>OL</sub> = 50 μA                        | 25°C             |             | 12             |     |             | 12             |     |       |
| $V_{OL}$          | Low-level output voltage                                | V <sub>IC</sub> = 2.5 V,                                | 500 4  | 25°C             |             | 120            |     |             | 120            |     | mV    |
|                   |   |   | $I_{OL} = 500 \mu\text{A}$                     | Full range       |             |                | 500 |             |                | 500 |       |
|                   | Large-signal<br>differential                            | V <sub>IC</sub> = 2.5 V,<br>V <sub>O</sub> = 1 V to 4 V | p 401 of                                       | 25°C             | 6           | 12             |     | 6           | 12             |     |       |
| $A_{VD}$          |   |   | $R_L = 10 \text{ k}\Omega^{\ddagger}$          | Full range       | 3           |                |     | 3           |                |     | V/mV  |
|                   | voltage amplification                                   | 10-1164   | $R_L = 1 M\Omega^{\ddagger}$                   | 25°C             |             | 800            |     |             | 800            |     |       |
| <sup>r</sup> i(d) | Differential input resistance                           |   | •  | 25°C             |             | 1012           |     |             | 1012           |     | Ω     |
| ri(c)             | Common-mode input resistance                            |   |  | 25°C             |             | 1012           |     |             | 1012           |     | Ω     |
| Ci(c)             | Common-mode input capacitance                           | f = 10 kHz,   |  | 25°C             |             | 5              |     |             | 5              |     | pF    |
| z <sub>O</sub>    | Closed-loop output impedance                            | f = 7 kHz,  | A <sub>V</sub> = 1                             | 25°C             |             | 200            |     |             | 200            |     | Ω     |
| CMRR              | Common-mode   | $V_{IC} = 0 \text{ to } 2.7 \text{ V},$                 | V <sub>O</sub> = 2.5 V,                        | 25°C             | 70          | 83             |     | 70          | 83             |     | dB    |
| CIVINK            | rejection ratio   | $R_S = 50 \Omega$                                       |  | Full range       | 70          |                |     | 70          |                |     | uБ    |
| ksvr              | Supply voltage rejection ratio                          | $V_{DD} = 4.4 \text{ V to 8 V},$ No load                | $V_{IC} = V_{DD}/2$                            | 25°C             | 80          | 95             |     | 80          | 95             |     | dB    |
|                   | (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )                   | 110 1000  |  | Full range       | 80          |                |     | 80          |                |     |       |
| I <sub>DD</sub>   | Supply current  | V <sub>O</sub> = 2.5 V,                                 | No load  | 25°C             |             | 13             | 25  | <u> </u>    | 13             | 25  | μΑ    |
| -טט               |   |   |  | Full range       |             |                | 30  |             |                | 30  | ,     |

<sup>†</sup> Full range for the TLV2711C is 0°C to 70°C. Full range for the TLV2711I is – 40°C to 85°C.

NOTE 5: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150$ °C extrapolated to  $T_A = 25$ °C using the Arrhenius equation and assuming an activation energy of 0.96 eV.



<sup>‡</sup>Referenced to 1.5 V

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# operating characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$ (unless otherwise noted)

|                    | PARAMETER                                   | TEST COND   | ITIONS  | <b>+</b> +       | Т     | LV27110 | С     | Т     | LV2711 | I     | UNIT               |  |
|--------------------|---|---|---|------------------|-------|---------|-------|-------|--------|-------|--------------------|--|
|                    | PARAWETER                                   | TEST COND   | ITIONS  | T <sub>A</sub> † | MIN   | TYP     | MAX   | MIN   | TYP    | MAX   | UNIT               |  |
|                    | Slew rate at unity gain                     | Va. 45 V to 25 V . D.   |   | D. 10 kgt        | 25°C  | 0.01    | 0.025 |       | 0.01   | 0.025 |                    |  |
| SR                 |   | $V_{O} = 1.5 \text{ V to } 3.5 \text{ V},  R_{L} = 10 \text{ k}\Omega^{\ddagger}, \\ C_{L} = 100 \text{ pF}^{\ddagger}$ |   | Full<br>range    | 0.005 |         |       | 0.005 |        |       | V/μs               |  |
| V                  | Equivalent input noise                      | f = 10 Hz   |   | 25°C             |       | 72      |       |       | 72     |       | ->///              |  |
| Vn                 | voltage                                     | f = 1 kHz   |   | 25°C             |       | 21      |       |       | 21     |       | nV/√Hz             |  |
| V                  | Peak-to-peak equivalent input noise voltage | f = 0.1 Hz to 1 Hz  |   | 25°C             |       | 600     |       |       | 600    |       | nV                 |  |
| V <sub>N(PP)</sub> |   | f = 0.1 Hz to 10 Hz   |   | 25°C             |       | 800     |       |       | 800    |       |                    |  |
| In                 | Equivalent input noise current              |   |   | 25°C             |       | 0.6     |       |       | 0.6    |       | fA/√ <del>Hz</del> |  |
|                    | Gain-bandwidth product                      | f = 10  kHz,<br>$C_L = 100 \text{ pF}^{\ddagger}$   | $R_L = 10 \text{ k}\Omega^{\ddagger}$ ,         | 25°C             |       | 65      |       |       | 65     |       | kHz                |  |
| ВОМ                | Maximum output-swing bandwidth              | $V_{O(PP)} = 2 V,$<br>$R_{L} = 10 \text{ k}\Omega^{\ddagger},$  | $A_V = 1,$<br>$C_L = 100 \text{ pF}^{\ddagger}$ | 25°C             |       | 7       |       |       | 7      |       | kHz                |  |
| φm                 | Phase margin at unity gain                  | R <sub>L</sub> = 10 kΩ <sup>‡</sup> ,   | C <sub>L</sub> = 100 pF‡                        | 25°C             |       | 60°     |       |       | 60°    | ·     |                    |  |
|                    | Gain margin                                 |   |   | 25°C             |       | 22      |       |       | 22     |       | dB                 |  |

<sup>†</sup>Full range is -40°C to 85°C.

# electrical characteristics at $V_{DD}$ = 3 V, $T_A$ = 25°C (unless otherwise noted)

|                   | DADAMETED  | TEG   | T CONDITIONS                |                                      | T    | LV2711Y        | ′   |        |  |
|-------------------|--|---|-----------------------------|--------------------------------------|------|----------------|-----|--------|--|
|                   | PARAMETER  | 163   | ST CONDITIONS               |                                      | MIN  | TYP            | MAX | UNIT   |  |
| ۷IO               | Input offset voltage   |   |                             |                                      |      | 0.47           |     | mV     |  |
| lio               | Input offset current   | $V_{DD\pm} = \pm 1.5 \text{ V},$<br>$R_S = 50 \Omega$ | $V_O = 0$ ,                 | $V_{IC} = 0$ ,                       |      | 0.5            |     | рΑ     |  |
| I <sub>IB</sub>   | Input bias current   | 115 - 00 22   |                             |                                      |      | 1              |     | pА     |  |
| VICR              | Common-mode input voltage range                                      | V <sub>IO</sub>   ≤5 mV,                              | $R_S = 50 \Omega$           |                                      |      | -0.3<br>to 2.2 |     | V      |  |
| V                 | High level output voltage  | High-level output voltage                             |                             |                                      | 2.94 |                |     |        |  |
| VOH               | High-level output voltage  | I <sub>OH</sub> = -200 μA                             |                             |                                      |      | 2.85           |     | V      |  |
| V/01              | Low lovel output voltage   | V <sub>IC</sub> = 0,                                  | I <sub>OL</sub> = 50 μA     |                                      |      | 15             |     | mV     |  |
| VOL               | Low-level output voltage   | V <sub>IC</sub> = 0,                                  | I <sub>OL</sub> = 500 μA    |                                      |      | 150            |     | 1117   |  |
| Δ                 | Large-signal differential  | V 4.5.V   |                             | $R_L = 10 \text{ k}\Omega^{\dagger}$ |      | 7              |     | V/mV   |  |
| AVD               | voltage amplification  | V <sub>IC</sub> = 1.5 V,                              | $V_O = 1 V \text{ to } 2 V$ | $R_L = 1 M\Omega^{\dagger}$          |      | 600            |     | V/IIIV |  |
| r <sub>i(d)</sub> | Differential input resistance  |   |                             |                                      |      | 1012           |     | Ω      |  |
| r <sub>i(c)</sub> | Common-mode input resistance   |   |                             |                                      |      | 1012           |     | Ω      |  |
| <sup>C</sup> i(c) | Common-mode input capacitance  | f = 10 kHz  |                             |                                      |      | 5              |     | pF     |  |
| z <sub>o</sub>    | Closed-loop output impedance   | f = 7 kHz,  | A <sub>V</sub> = 1          |                                      |      | 200            |     | Ω      |  |
| CMRR              | Common-mode rejection ratio  | $V_{IC} = 0 \text{ to } 1.7 \text{ V},$               | V <sub>O</sub> = 1.5 V,     | R <sub>S</sub> = 50 Ω                |      | 83             |     | dB     |  |
| kSVR              | Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> ) | V <sub>DD</sub> = 2.7 V to 8 V,                       | $V_{IC} = V_{DD}/2,$        | No load                              |      | 95             |     | dB     |  |
| I <sub>DD</sub>   | Supply current   | V <sub>O</sub> = 1.5 V,                               | No load                     | ·                                    |      | 11             |     | μΑ     |  |

<sup>†</sup> Referenced to 1.5 V



<sup>‡</sup>Referenced to 1.5 V

# electrical characteristics at $V_{DD}$ = 5 V, $T_A$ = 25°C (unless otherwise noted)

| DADAMETED         |  | 756  | CT CONDITIONS               |                                      | TI  | <i>'</i>       |     |       |
|-------------------|--|--|-----------------------------|--------------------------------------|-----|----------------|-----|-------|
|                   | PARAMETER  | l les  | ST CONDITIONS               |                                      | MIN | TYP            | MAX | UNIT  |
| VIO               | Input offset voltage   |  |                             |                                      |     | 0.45           |     | mV    |
| I <sub>IO</sub>   | Input offset current   | $V_{DD} \pm = \pm 2.5 \text{ V},$<br>$R_{S} = 50 \Omega$ | $V_{IC} = 0$ ,              | $V_O = 0$ ,                          |     | 0.5            |     | рА    |
| I <sub>IB</sub>   | Input bias current   | 11/5 = 30 22   |                             |                                      |     | 1              |     | рА    |
| VICR              | Common-mode input voltage range                                      | V <sub>IO</sub>   ≤5 mV,                                 | R <sub>S</sub> = 50 Ω       |                                      |     | -0.3<br>to 4.2 |     | V     |
| \/-··             | High level output voltage  | I <sub>OH</sub> = -100 μA                                |                             |                                      |     | 4.95           |     | V     |
| VOH               | High-level output voltage  | $I_{OH} = -250 \mu\text{A}$                              |                             |                                      |     | 4.875          |     | V     |
| \/-·              | Low lovel output voltage   | V <sub>IC</sub> = 2.5 V,                                 | I <sub>OL</sub> = 50 μA     |                                      |     | 12             |     | mV    |
| VOL               | Low-level output voltage   | V <sub>IC</sub> = 2.5 V,                                 | I <sub>OL</sub> = 500 μA    |                                      |     | 120            |     | IIIV  |
| _                 | Large-signal differential  | V 05.V   |                             | $R_L = 10 \text{ k}\Omega^{\dagger}$ |     | 12             |     | \//\/ |
| AVD               | voltage amplification  | $V_{IC} = 2.5 V,$  | $V_O = 1 V \text{ to } 4 V$ | $R_L = 1 M\Omega^{\dagger}$          | 800 |                |     | V/mV  |
| r <sub>i(d)</sub> | Differential input resistance  |  |                             | •                                    |     | 1012           |     | Ω     |
| r <sub>i(c)</sub> | Common-mode input resistance   |  |                             |                                      |     | 1012           |     | Ω     |
| <sup>C</sup> i(c) | Common-mode input capacitance  | f = 10 kHz   |                             |                                      |     | 5              |     | pF    |
| z <sub>o</sub>    | Closed-loop output impedance   | f = 7 kHz,   | A <sub>V</sub> = 1          |                                      |     | 200            |     | Ω     |
| CMRR              | Common-mode rejection ratio  | $V_{IC} = 0 \text{ to } 2.7 \text{ V},$                  | V <sub>O</sub> = 2.5 V,     | $R_S = 50 \Omega$                    |     | 83             |     | dB    |
| ksvr              | Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> ) | V <sub>DD</sub> = 4.4 V to 8 V,                          | $V_{IC} = V_{DD}/2,$        | No load                              |     | 95             |     | dB    |
| I <sub>DD</sub>   | Supply current   | V <sub>O</sub> = 2.5 V,                                  | No load                     |                                      |     | 13             |     | μА    |

<sup>†</sup>Referenced to 1.5 V

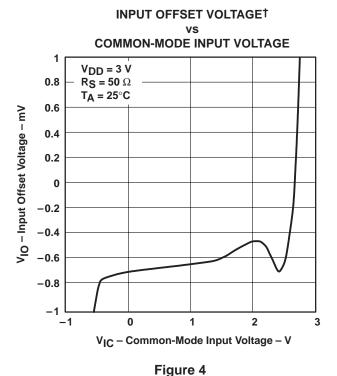
### **Table of Graphs**

|                                  |  |   | FIGURE                 |
|----------------------------------|--|---|------------------------|
| VIO                              | Input offset voltage   | Distribution vs Common-mode input voltage                     | 2, 3<br>4, 5           |
| ανιο                             | Input offset voltage temperature coefficient                     | Distribution  | 6, 7                   |
| I <sub>IB</sub> /I <sub>IO</sub> | Input bias and input offset currents                             | vs Free-air temperature                                       | 8                      |
| VI                               | Input voltage  | vs Supply voltage<br>vs Free-air temperature                  | 9<br>10                |
| Vон                              | High-level output voltage  | vs High-level output current                                  | 11, 14                 |
| VOL                              | Low-level output voltage   | vs Low-level output current                                   | 12, 13, 15             |
| VO(PP)                           | Maximum peak-to-peak output voltage                              | vs Frequency  | 16                     |
| los                              | Short-circuit output current                                     | vs Supply voltage vs Free-air temperature                     | 17<br>18               |
| ٧o                               | Output voltage   | vs Differential input voltage                                 | 19, 20                 |
| AVD                              | Large-signal differential voltage amplification and phase margin | vs Load resistance<br>vs Frequency<br>vs Free-air temperature | 21<br>22, 23<br>24, 25 |
| z <sub>O</sub>                   | Output impedance   | vs Frequency  | 26, 27                 |
| CMRR                             | Common-mode rejection ratio                                      | vs Frequency<br>vs Free-air temperature                       | 28<br>29               |
| ksvr                             | Supply-voltage rejection ratio                                   | vs Frequency<br>vs Free-air temperature                       | 30, 31<br>32           |
| I <sub>DD</sub>                  | Supply current   | vs Supply voltage   | 33                     |
| SR                               | Slew rate  | vs Load capacitance vs Free-air temperature                   | 34<br>35               |
|                                  | Large-signal pulse response                                      |   | 36, 37, 38, 39         |
| ٧o                               | Inverting small-signal pulse response                            | vs Time   | 40, 41                 |
|                                  | Small-signal pulse response                                      |   | 42, 43                 |
| V <sub>n</sub>                   | Equivalent input noise voltage                                   | vs Frequency  | 44, 45                 |
|                                  | Noise voltage (referred to input)                                | Over a 10-second period                                       | 46                     |
| THD + N                          | Total harmonic distortion plus noise                             | vs Frequency  | 47                     |
|                                  | Gain-bandwidth product   | vs Free-air temperature vs Supply voltage                     | 48<br>49               |
| φm                               | Phase margin   | vs Frequency<br>vs Load capacitance                           | 23, 24<br>50           |
|                                  | Gain margin  | vs Load capacitance   | 51                     |
| B <sub>1</sub>                   | Unity-gain bandwidth   | vs Load capacitance   | 52                     |



## **DISTRIBUTION OF TLV2711 INPUT OFFSET VOLTAGE** 546 Amplifiers From 1 Wafer Lot $V_{DD} = \pm 1.5 V$ T<sub>A</sub> = 25°C 20 Precentage of Amplifiers - % 15 10 5 -0.9 -0.5 -0.1 0.3 -1.3 0.7 1.1 1.5 VIO - Input Offset Voltage - mV

Figure 2



DISTRIBUTION OF TLV2711
INPUT OFFSET VOLTAGE

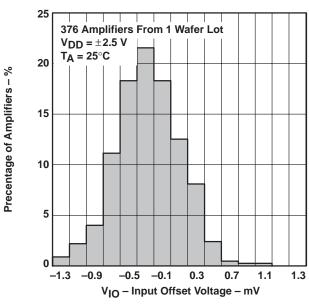


Figure 3

# INPUT OFFSET VOLTAGE† vs COMMON-MODE INPUT VOLTAGE

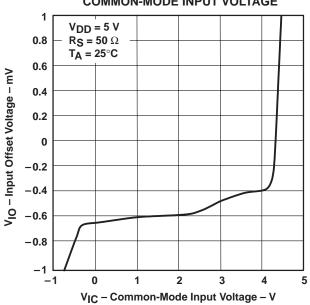


Figure 5

 $\dagger$  For all curves where  $V_{DD}$  = 5 V, all loads are referenced to 2.5 V. For all curves where  $V_{DD}$  = 3 V, all loads are referenced to 1.5 V.



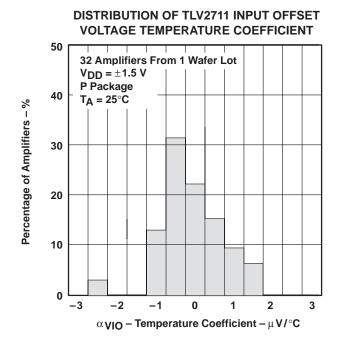
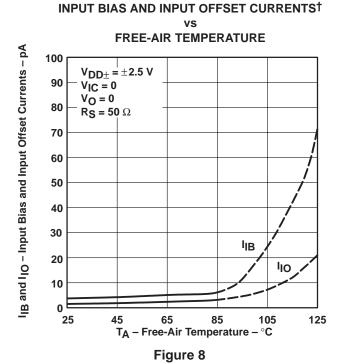


Figure 6



**DISTRIBUTION OF TLV2711 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT** 

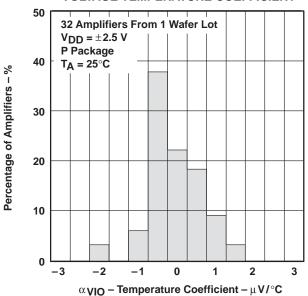
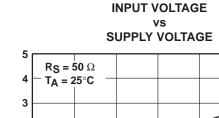


Figure 7



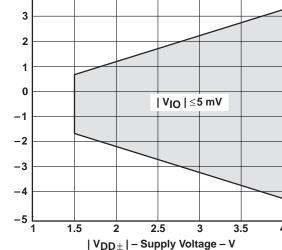


Figure 9

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



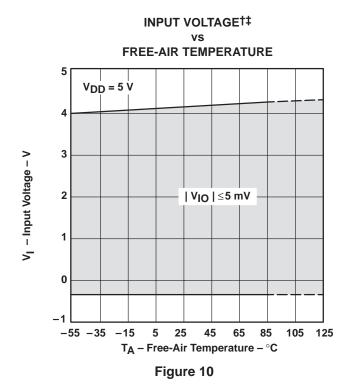
V<sub>I</sub> - Input Voltage - V

HIGH-LEVEL OUTPUT VOLTAGE†‡

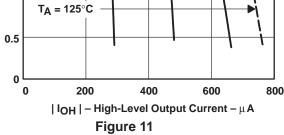
#### TYPICAL CHARACTERISTICS

1.5

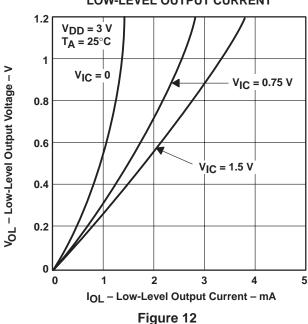
T<sub>A</sub> = 85°C



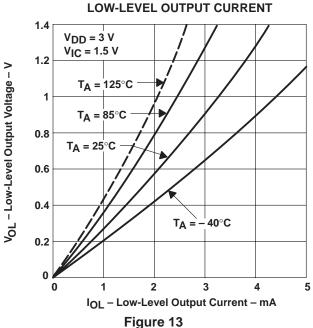
# **HIGH-LEVEL OUTPUT CURRENT** $V_{DD} = 3 V$ 2.5 VOH - High-Level Output Voltage - V $T_A = -40^{\circ}C$ 2 T<sub>A</sub> = 25°C







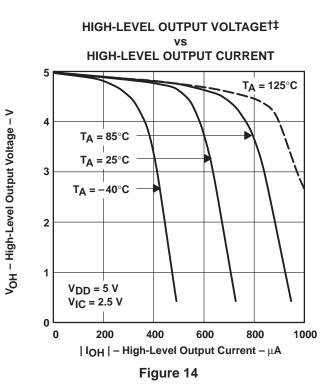
# LOW-LEVEL OUTPUT VOLTAGE†‡

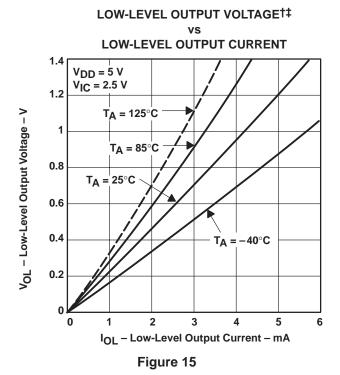


<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

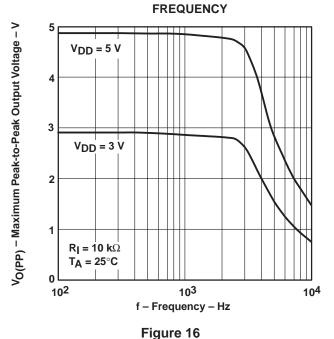
<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.







# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE‡



# SHORT-CIRCUIT OUTPUT CURRENT

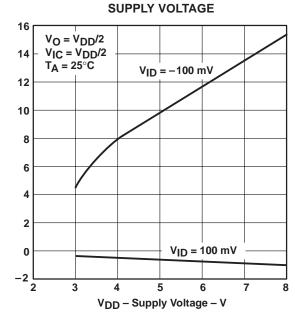


Figure 17

<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.

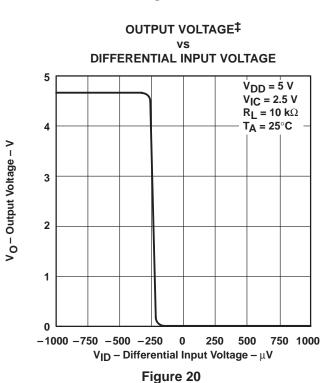


IOS - Short-Circuit Output Current - mA

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

### SHORT-CIRCUIT OUTPUT CURRENT†‡ FREE-AIR TEMPERATURE 14 V<sub>DD</sub> = 5 V V<sub>IC</sub> = 2.5 V IOS - Short-Circuit Output Current - mA 12 V<sub>O</sub> = 2.5 V 10 $V_{ID} = -100 \text{ mV}$ 8 2 $V_{ID} = 100 \text{ mV}$ 0 \_ -75 -50 25 75 100 125 TA - Free-Air Temperature - °C

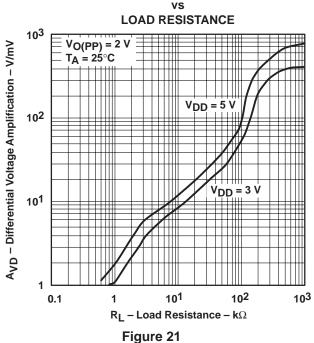
Figure 18



**OUTPUT VOLTAGE**‡ **DIFFERENTIAL INPUT VOLTAGE** 3  $V_{DD} = 3'V$  $R_I = 10 \text{ k}\Omega$  $V_{IC} = 1.5 \text{ V}$ 2.5  $T_A = 25^{\circ}C$ V<sub>O</sub> – Output Voltage – V 2 1.5 0.5 -1000 -750 -500 -250 0 250 500 750 1000 V<sub>ID</sub> - Differential Input Voltage - μV

# DIFFERENTIAL VOLTAGE AMPLIFICATION<sup>‡</sup>

Figure 19



<sup>†</sup>Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.



# LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†

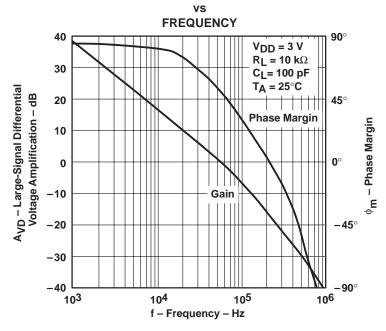


Figure 22

# LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN<sup>†</sup>

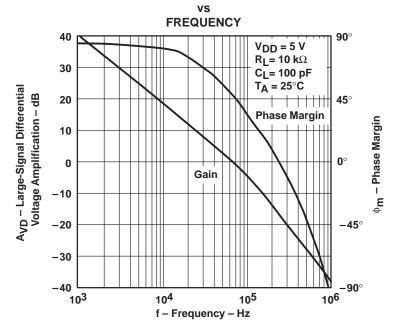
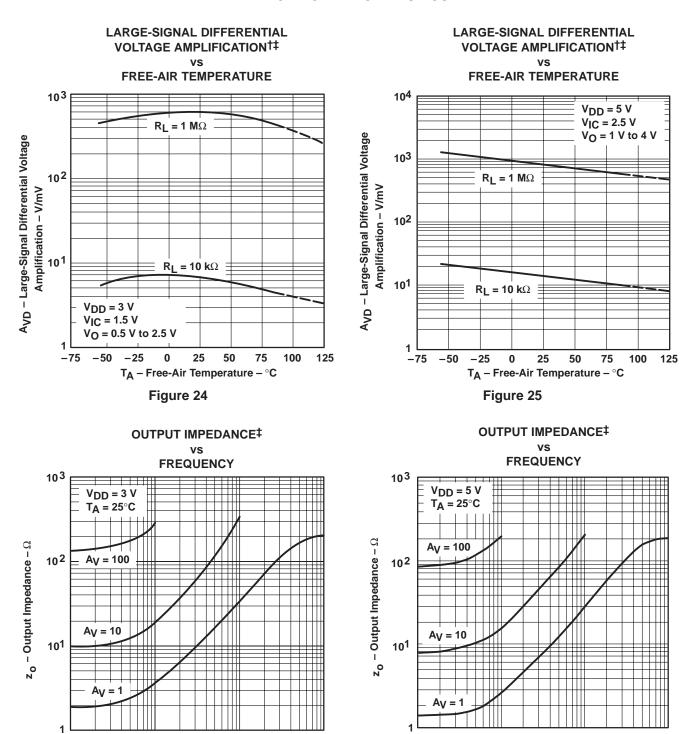


Figure 23

† For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.





104

101

102

f- Frequency - Hz

Figure 26

103

<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.



101

102

Figure 27

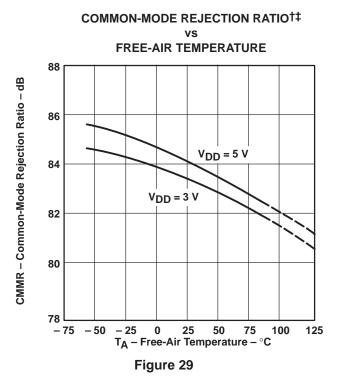
f- Frequency - Hz

103

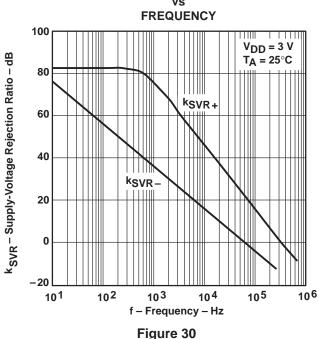
104

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

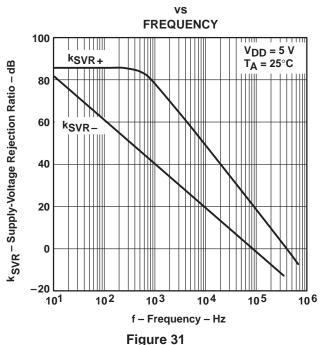
# **COMMON-MODE REJECTION RATIO**† **FREQUENCY** 100 T<sub>A</sub> = 25°C CMRR - Common-Mode Rejection Ratio - dB $V_{DD} = 5 V$ $V_0 = 2.5 \text{ V}$ 80 $V_{DD} = 3 V$ 60 $V_0 = 1.5 \text{ V}$ 40 20 101 102 104 f - Frequency - Hz Figure 28



## SUPPLY-VOLTAGE REJECTION RATIO† vs



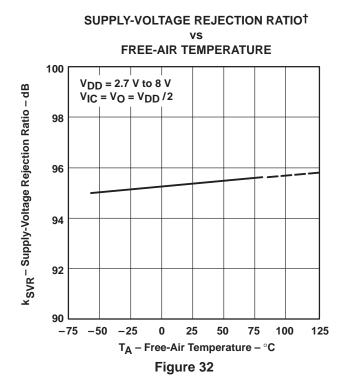
## SUPPLY-VOLTAGE REJECTION RATIO†

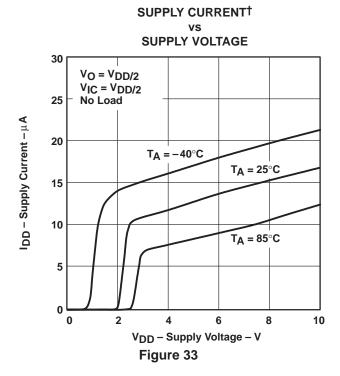


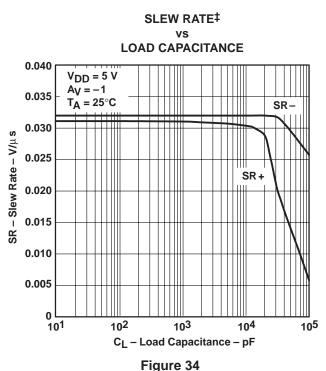
<sup>†</sup> For all curves where  $V_{DD} = 5$  V, all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3$  V, all loads are referenced to 1.5 V.

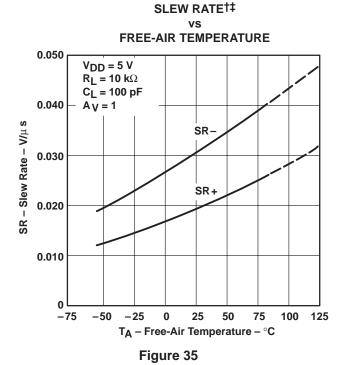
<sup>‡</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.











<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.



# 



Figure 36

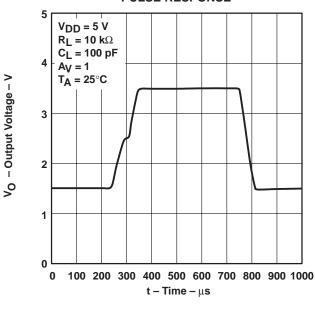
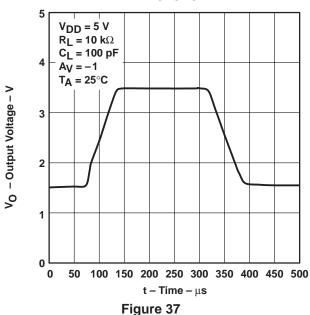
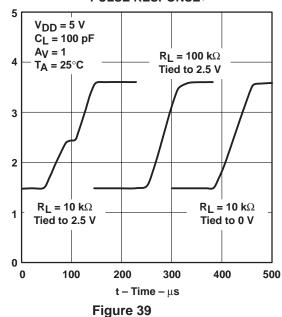


Figure 38

# INVERTING LARGE-SIGNAL PULSE RESPONSE†



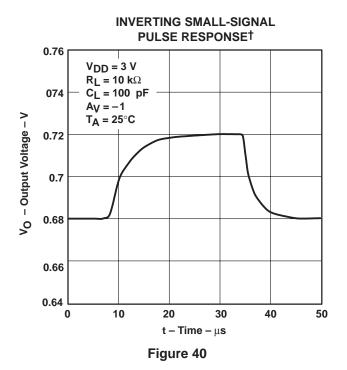
# VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE<sup>†</sup>

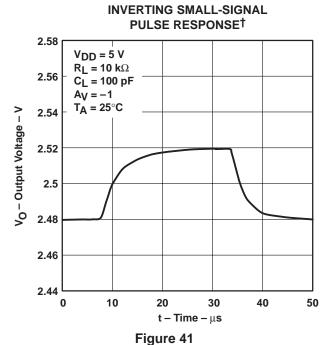


† For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.



Vo - Output Voltage - V







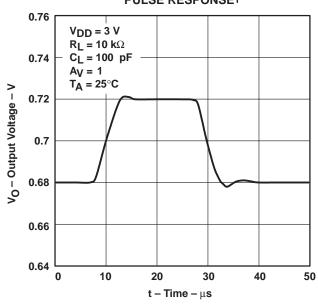


Figure 42

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE†

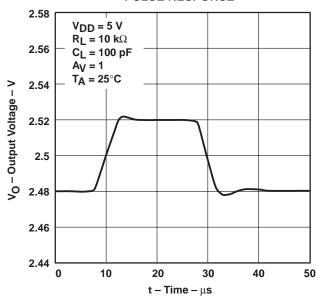
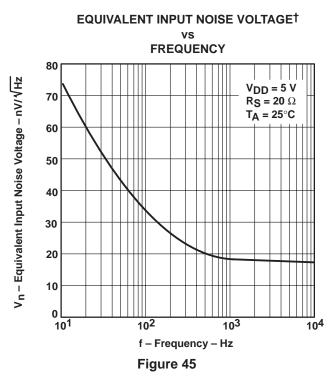


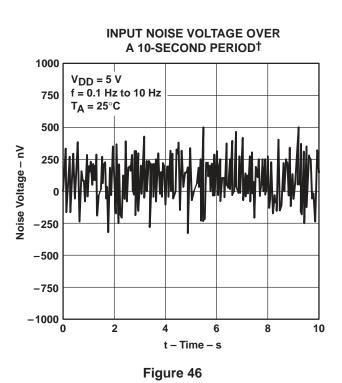
Figure 43

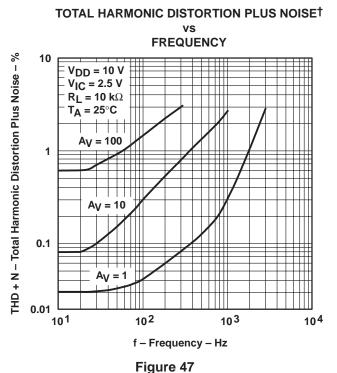
 $\dagger$  For all curves where  $V_{DD}$  = 5 V, all loads are referenced to 2.5 V. For all curves where  $V_{DD}$  = 3 V, all loads are referenced to 1.5 V.



## **EQUIVALENT INPUT NOISE VOLTAGE**<sup>†</sup> **FREQUENCY** 80 V<sub>n</sub> – Equivalent Input Noise Voltage – nV/ √Hz $V_{DD} = 3 V$ $R_S = 20 \Omega$ 70 T<sub>A</sub> = 25°C 60 50 40 30 20 10 101 102 103 104 f - Frequency - Hz Figure 44

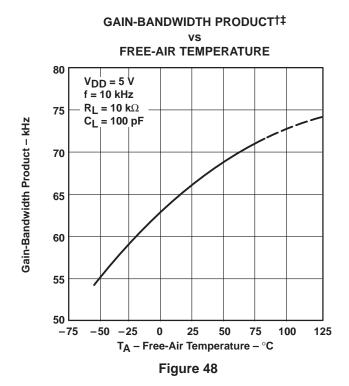


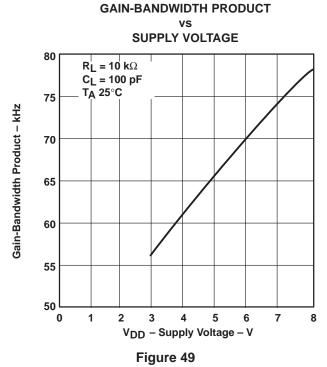


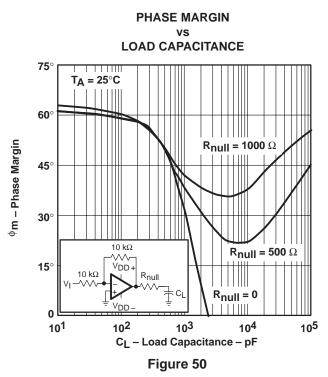


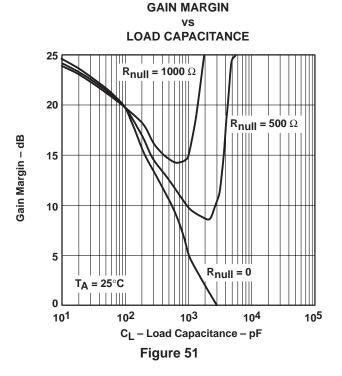
† For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.











<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where V<sub>DD</sub> = 5 V, all loads are referenced to 2.5 V. For all curves where V<sub>DD</sub> = 3 V, all loads are referenced to 1.5 V.



# UNITY-GAIN BANDWIDTH vs

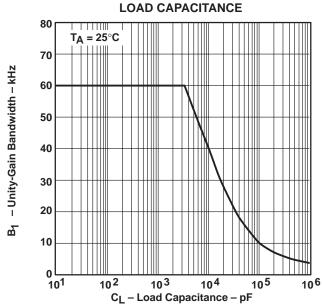


Figure 52

#### **APPLICATION INFORMATION**

#### driving large capacitive loads

The TLV2711 is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 50 and Figure 51 illustrate its ability to drive loads up to 600 pF while maintaining good gain and phase margins  $(R_{null} = 0)$ .

A smaller series resistor ( $R_{null}$ ) at the output of the device (see Figure 53) improves the gain and phase margins when driving large capacitive loads. Figure 50 and Figure 51 show the effects of adding series resistances of 500  $\Omega$  and 1000  $\Omega$ . The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, equation 1 can be used.

$$\Delta \phi_{\text{m1}} = \tan^{-1} \left( 2 \times \pi \times \text{UGBW} \times R_{\text{null}} \times C_{\text{L}} \right)$$
 (1)

Where:

 $\Delta \phi_{m1}$  = Improvement in phase margin

UGBW = Unity-gain bandwidth frequency

R<sub>null</sub> = Output series resistance

 $C_1$  = : Load capacitance



#### APPLICATION INFORMATION

#### driving large capacitive loads (continued)

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 52). To use equation 1, UGBW must be approximated from Figure 52.

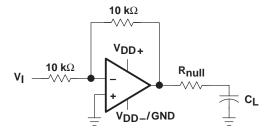


Figure 53. Series-Resistance Circuit

#### driving heavy dc loads

The TLV2711 is designed to provide better sinking and sourcing output currents than earlier CMOS rail-to-rail output devices. This device is specified to sink 500  $\mu$ A and source 250  $\mu$ A at V<sub>DD</sub> = 3 V and V<sub>DD</sub> = 5 V at a maximum quiescent I<sub>DD</sub> of 25  $\mu$ A. This provides a greater than 90% power efficiency.

When driving heavy dc loads, such as  $10 \text{ k}\Omega$ , the positive edge under slewing conditions can experience some distortion. This condition can be seen in Figure 38. This condition is affected by three factors.

- Where the load is referenced. When the load is referenced to either rail, this condition does not occur. The distortion occurs only when the output signal swings through the point where the load is referenced. Figure 39 illustrates two  $10-k\Omega$  load conditions. The first load condition shows the distortion seen for a  $10-k\Omega$  load tied to 2.5 V. The third load condition shows no distortion for a  $10-k\Omega$  load tied to 0 V.
- Load resistance. As the load resistance increases, the distortion seen on the output decreases. Figure 39 illustrates the difference seen on the output for a  $10-k\Omega$  load and a  $100-k\Omega$  load with both tied to 2.5 V.
- Input signal edge rate. Faster input edge rates for a step input result in more distortion than with slower input edge rates.



#### **APPLICATION INFORMATION**

#### macromodel information

Macromodel information provided was derived using Microsim  $Parts^{TM}$ , the model generation software used with Microsim  $PSpice^{TM}$ . The Boyle macromodel (see Note 6) and subcircuit in Figure 54 are generated using the TLV2711 typical electrical and operating characteristics at  $T_A = 25$ °C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 6: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

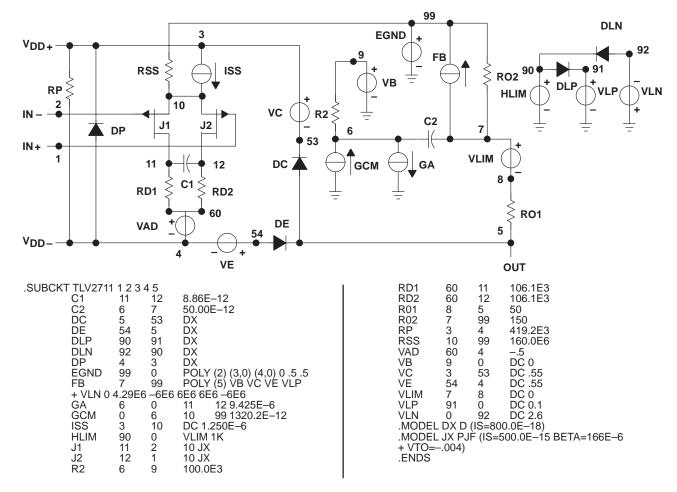


Figure 54. Boyle Macromodel and Subcircuit

PSpice and Parts are trademark of MicroSim Corporation.



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#### PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| TLV2711CDBVR     | ACTIVE     | SOT-23       | DBV                | 5    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | 0 to 70      | VAJC                 | Samples |
| TLV2711CDBVT     | ACTIVE     | SOT-23       | DBV                | 5    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM |              | VAJC                 | Samples |
| TLV2711IDBVR     | ACTIVE     | SOT-23       | DBV                | 5    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | VAJI                 | Samples |
| TLV2711IDBVT     | ACTIVE     | SOT-23       | DBV                | 5    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM |              | VAJI                 | Samples |
| TLV2711IDBVTG4   | LIFEBUY    | SOT-23       | DBV                | 5    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM |              | VAJI                 |         |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### PACKAGE OPTION ADDENDUM

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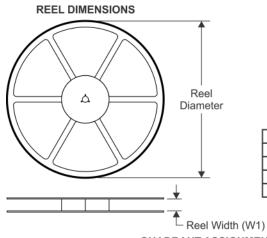
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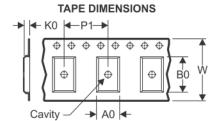
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## PACKAGE MATERIALS INFORMATION

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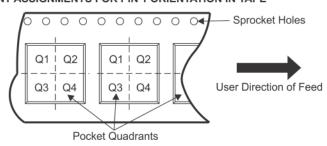
### TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| All dimensions are nominal |                 |                    |   |      |                          |                          |            |            |            |            |           |                  |
|----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                     | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| TLV2711CDBVR               | SOT-23          | DBV                | 5 | 3000 | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TLV2711CDBVT               | SOT-23          | DBV                | 5 | 250  | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TLV2711IDBVR               | SOT-23          | DBV                | 5 | 3000 | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TLV2711IDBVT               | SOT-23          | DBV                | 5 | 250  | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |

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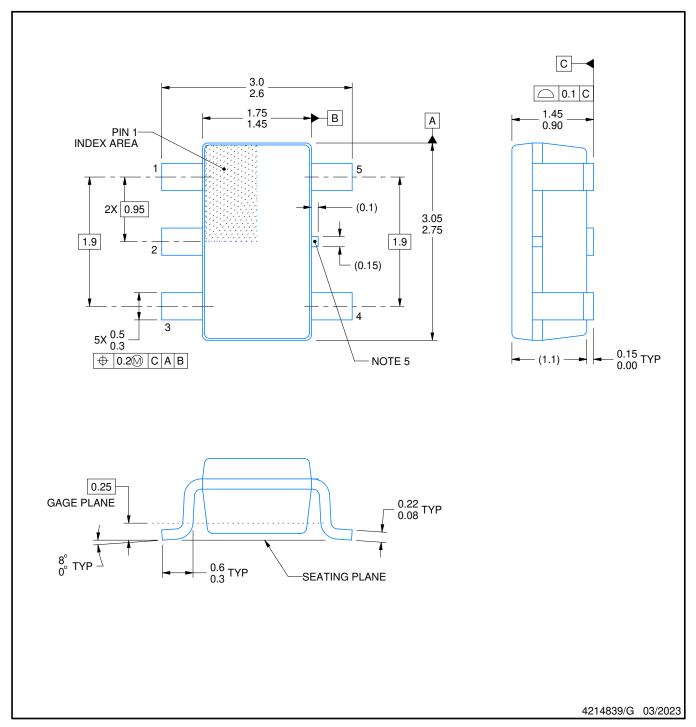


\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV2711CDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| TLV2711CDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| TLV2711IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| TLV2711IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |



SMALL OUTLINE TRANSISTOR



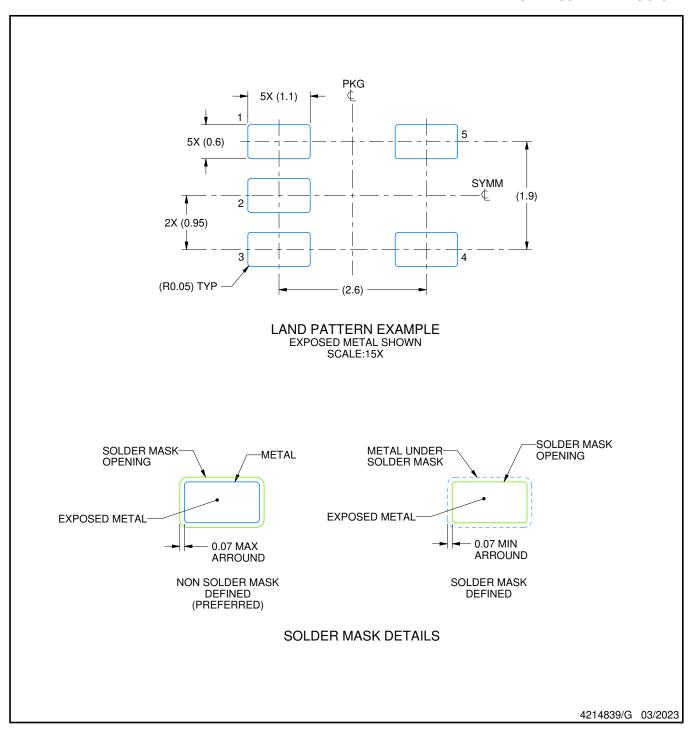
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR

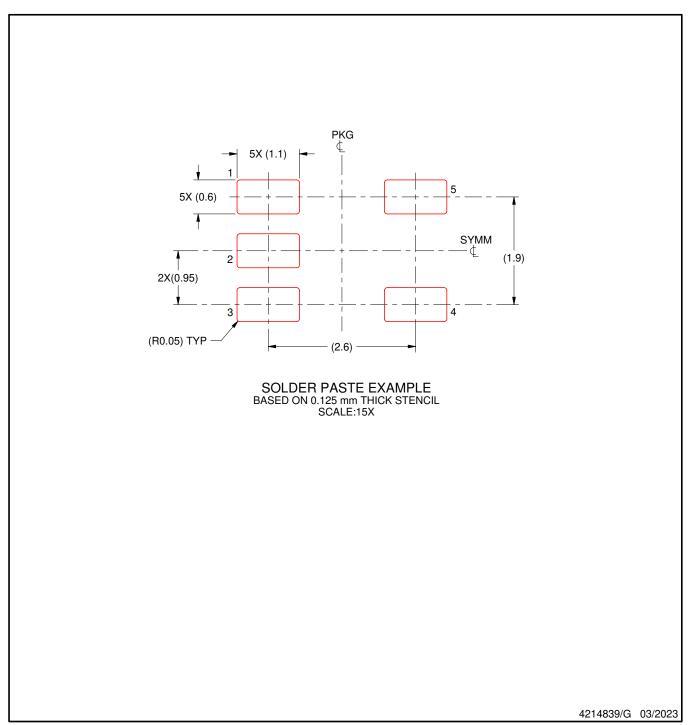


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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